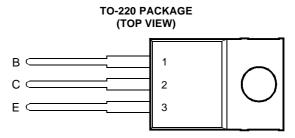
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- Designed for Complementary Use with BDX54, BDX54A, BDX54B and BDX54C
- 60 W at 25°C Case Temperature
- 8 A Continuous Collector Current
- Minimum h_{FE} of 750 at 3 V, 3 A



Pin 2 is in electrical contact with the mounting base.

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT	
	BDX53		45	
Collector-base voltage ($I_E = 0$)	BDX53A	N/	60	V
	BDX53B	V _{CBO}	80	v
	BDX53C		100	
	BDX53		45	
Callector emitter veltere (L 0)	BDX53A	N/	60	V
Collector-emitter voltage ($I_B = 0$)	BDX53B	V _{CEO}	80	v
	BDX53C		100	
Emitter-base voltage	V _{EBO}	5	V	
Continuous collector current		Ι _C	8	A
Continuous base current	I _B	0.2	A	
Continuous device dissipation at (or below) 25°C case temperature (see Note 1	P _{tot}	60	W	
Continuous device dissipation at (or below) 25°C free air temperature (see Note	P _{tot}	2	W	
Operating junction temperature range	Тj	-65 to +150	°C	
Operating temperature range	T _{stg}	-65 to +150	°C	
Operating free-air temperature range	T _A	-65 to +150	°C	

NOTES: 1. Derate linearly to 150°C case temperature at the rate of 0.48 W/°C.

2. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.





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electrical characteristics at 25°C case temperature (unless otherwise noted)

	PARAMETER		TES	T CONDITIONS		MIN	TYP	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C = 100 mA	I _B = 0	(see Note 3)	BDX53 BDX53A BDX53B BDX53C	45 60 80 100			V
I _{CEO}	Collector-emitter cut-off current	$V_{CE} = 30 V$ $V_{CE} = 30 V$ $V_{CE} = 40 V$ $V_{CE} = 50 V$	$I_{B} = 0$ $I_{B} = 0$ $I_{B} = 0$ $I_{B} = 0$		BDX53 BDX53A BDX53B BDX53C			0.5 0.5 0.5 0.5	mA
I _{CBO}	Collector cut-off current	$V_{CB} = 45 V$ $V_{CB} = 60 V$ $V_{CB} = 80 V$ $V_{CB} = 100 V$	$I_{E} = 0$ $I_{E} = 0$ $I_{E} = 0$ $I_{E} = 0$		BDX53 BDX53A BDX53B BDX53C			0.2 0.2 0.2 0.2	mA
I _{EBO}	Emitter cut-off current	V _{EB} = 5 V	$I_{\rm C} = 0$					2	mA
h _{FE}	Forward current transfer ratio	V _{CE} = 3 V	I _C = 3 A	(see Notes 3 and 4)		750			
V _{BE(sat)}	Base-emitter saturation voltage	I _B = 12 mA	I _C = 3 A	(see Notes 3 and 4)				2.5	V
V _{CE(sat)}	Collector-emitter saturation voltage	I _B = 12 mA	I _C = 3 A	(see Notes 3 and 4)				2	V
V_{EC}	Parallel diode forward voltage	I _E = 3 A	$I_B = 0$					2.5	V

NOTES: 3. These parameters must be measured using pulse techniques, t_p = 300 µs, duty cycle \leq 2%.

4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

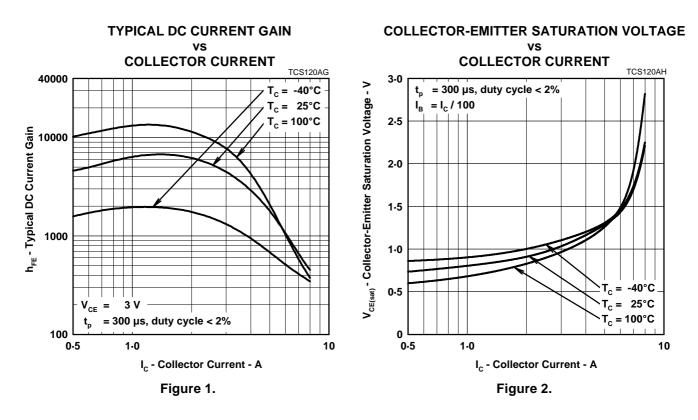
PARAMETER			TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			2.08	°C/W
R_{\thetaJA}	Junction to free air thermal resistance			62.5	°C/W

resistive-load-switching characteristics at 25°C case temperature

	PARAMETER	TEST CONDITIONS [†]			MIN	ТҮР	MAX	UNIT
t _{on}	Turn-on time	I _C = 3 A	$I_{B(on)} = 12 \text{ mA}$	$I_{B(off)} = -12 \text{ mA}$		1		μs
t _{off}	Turn-off time	$V_{BE(off)} = -4.5 V$	$R_L = 10 \ \Omega$	t_p = 20 μ s, dc \leq 2%		5		μs

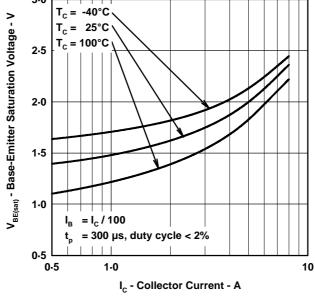
[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

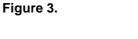
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TYPICAL CHARACTERISTICS

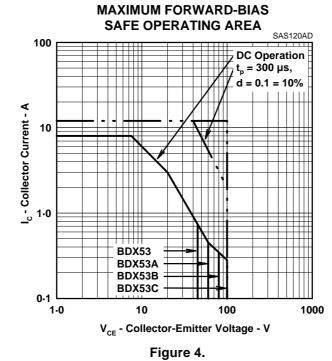
BASE-EMITTER SATURATION VOLTAGE vs COLLECTOR CURRENT $T_c = -40^{\circ}C$ $T_c = 25^{\circ}C$



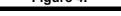




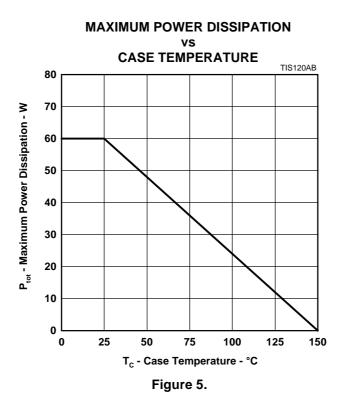
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MAXIMUM SAFE OPERATING REGIONS







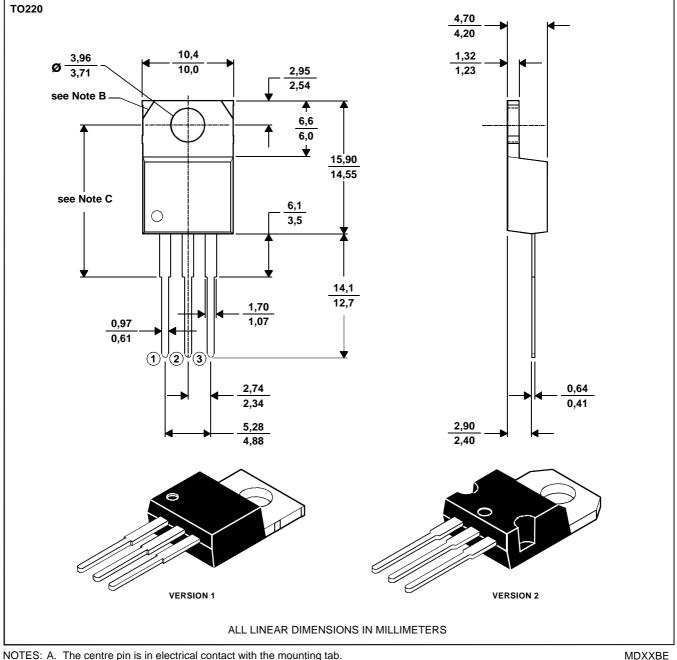
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MECHANICAL DATA

TO-220

3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



B. Mounting tab corner profile according to package version.

C. Typical fixing hole centre stand off height according to package version.

Version 1, 18.0 mm. Version 2, 17.6 mm.



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